Planar Reflective Phaser and Synthesis for Radio Analog Signal Processing (R-ASP)

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A planar reflective phaser based on an open-ended edge-coupled-line structure is proposed. This phaser is the first reported phaser that combines the benefits of high resolution, inherent to cross-coupled resonator reflective phasers, and of compactness, inherent to planar circuits. A 4-ns swing 4.9-5.5 GHz quadratic phase (linear group delay) 4^{th}-order microstrip phaser is synthesized and experimentally demonstrated. Given its advantages, this phaser may find vast applications in Radio Analog Signal Processing (R-ASP) systems.

Introduction: Emerging Radio Analog Signal Processing (R-ASP) technology, which consists in manipulating signals in their pristine analog and real-time form, represents a novel and promising approach for future millimeter-wave and terahertz communication, radar, sensing and imaging systems [1]. Compared to conventional digital signal processing (DSP) based technologies, R-ASP offers indeed the benefits of higher speed, lower cost and lower consumption, especially when deployed at millimeter-wave frequencies. R-ASP applications reported so far include pulse position modulators [2], compressive receivers [3], real-time spectrum analyzers [4], real-time spectrogram analyzers [5], waveform synthesisers [6], and chipless RFIDs [7], to name just a few.

The core element in R-ASP is the "phaser" [1], a component providing a highly flexible and controllable frequency dependent group delay response, and which may be transmission-type or reflection-type structures. In the former catergory is the C-section phaser [8], whose processing resolution, defined as the group delay swing – bandwidth product, $\sigma = \Delta\tau\Delta\omega$, is restricted by practically achievable coupling levels. A CRLH C-section, leveraging CRLH coupling enhancement, was proposed was proposed in [9] to boost this resolution, but this was at the expense of higher design complexity. On the other hand, reflection-type phasers provide higher resolution [10], but must be combined with circulators or a couplers for reflection to transmission response transformation. They may be realized in planar Bragg grating technology [4], but this approach suffers from group delay oscillations due to multiple internal reflections. To remedy this issue, a coupled-resonator based reflective phaser was introduced in [10]. This phaser exhibits excellent characteristics but it was realized in bulky rectangular waveguide technology.

This paper presents a planar alternative to the reflective phaser of [10]. The proposed phaser is an open-ended edge-coupled transmission line structure, which benefits from all the benefits of planar circuits.

Principle: We select here a side-coupled half-wavelength resonator configuration, where each of the cascaded resonators are juxtaposed with the two resonators, as this configuration is more compact than the end-coupled resonator one and does not suffer from even-harmonic parasitic response [11]. Moreover, we choose an edge coupling, as opposed to broadside coupling, for circuit uniplanarity [11, 12].

Figure 1 shows the topology of an n^{th}-order open-ended reflective phaser based on edge-coupled resonators. Each coupled-section is a two-port network obtained by opening two diagonally opposite ports of a four-port coupled-line coupler [12]. The key electrical parameters for the i^{th} coupled-section are the even- and odd-mode characteristic impedances, Z_e^i and Z_o^i. The first and last sections have the same characteristic impedance as that of the external system, Z_0, and all the sections have an electrical length of $\theta = \pi/2$ at the resonance frequency, ω_0.

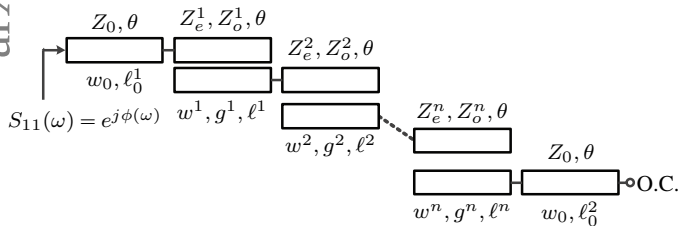

Fig. 1: Topology of an n^{th}-order reflective planar phaser composed of edge-coupled resonators.

The synthesis of the desired group delay response, $\tau(\omega) = -\partial\phi(\omega)/\partial\omega$ for $\omega_L \leqslant \omega \leqslant \omega_H$, where $\phi(\omega) = \angle\{S_{11}(\omega)\}$ and where $|S_{11}(\omega)| = 1$ due to the purely reflective nature of the device, follows the procedure established in [10], based on the equivalent circuits shown in Fig. 1 [12].

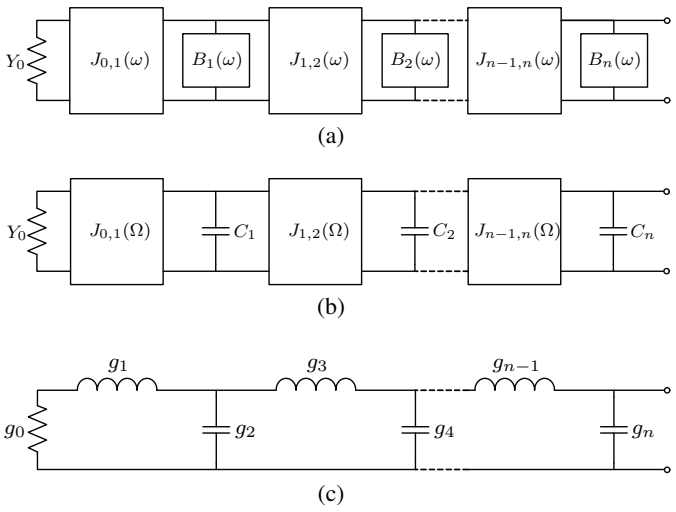

Fig. 2: Equivalent circuits for the planar reflective phaser of Fig. 1. (a) Bandpass distributed equivalent circuit, with response $S_{11}(\omega) = \exp[j\phi(\omega)]$. (b) Lowpass $(0 \leqslant \Omega \leqslant 1)$ equivalent circuit with admittance inverters, $J_{i-1,i}$, $i = 1, 2, \ldots, n$. (c) Corresponding fully-lumped prototype.

Figure 2(a) is the bandpass equivalent circuit of the phaser, with center frequency ω_0, where the half-wavelength resonators are modeled by distributed susceptances, $B_i(\omega)$, and the couplings between these resonators are modeled by admittance-inverters, $J_{i,i+1}(\omega)$. Figure 2(b) is the normalized frequency, $0 \leqslant \Omega \leqslant 1$, low-pass equivalent circuit, with admittance-inverters and lumped capacitors, and Fig. 2(c) is the corresponding prototype, with unity input impedance $g_0 = 1$.

The synthesis is performed as follows. First, the bandpass frequencies and corresponding phases, pertaining to Fig. 2(a), are discretized, $\omega \to \omega_i$ and $\phi \to \phi_i$, with $i = 0, 1, 2, \ldots, n$. Second, ω_i and ϕ_i are mapped onto their lowpass counterparts, Ω_i and Φ_i with $0 \leqslant \Omega_i \leqslant 1$ corresponding to the Fig. 2(b), using the mapping function $\Omega_i = \tan(\pi\omega_i/\omega_0)/\tan(\pi\omega_n/\omega_n)$. Third, a Hurwitz polynomial, $H(s)$ where $s = j\Omega$, realizing the phase function $\Phi(\Omega)$ at the discretized points is constructed using a recurrence formula (given in [10]). Since $|S_{11}| = 1$ and $\angle\{S_{11}\} = \phi(\omega)$, S_{11} has the polynomial form $S_{11}(s) = H(-s)/H(s)$, so that $z(s) = (1 - S_{11})/(1 + S_{11}) = [H(s) - H(-s)]/[H(s) + H(-s)] = H_o(s)/H_e(s)$, where $H_o(s)$ and $H_e(s)$ are the even and odd parts of $H(s)$, respectively. Then, fourth, this polynomial expression of $z(s)$ is mapped onto the input impedance of Fig. 2(c), which provides the parameters g_i. Fifth, the parameters in 2(b) are computed from the g_i's as

$$J_{0,1} = \sqrt{\frac{Y_0 C_1}{g_0 g_1}} = Y_0\sqrt{\frac{B}{g_1}}, \quad J_{i-1,i} = \sqrt{\frac{C_{i-1}C_i}{g_{i-1}g_i}} = Y_0\frac{B}{\sqrt{g_{i-1}g_i}}, \quad \text{(1a)}$$

with

$$C_i = Y_0 \tan\left(\pi\frac{\omega_n}{\omega_0}\right), \quad B_i = B = \tan\left(\pi\frac{\omega_n}{\omega_0}\right), \quad \forall i, \quad \text{(1b)}$$

where $Y_0 = 1/Z_0 = 50\ \Omega$. The parameters C_i and B_i are the same for all $i's$ because all the resonators are synchronously tuned at ω_0, which may be chosen to be either ω_L or ω_H. Finally, sixth, the electrical parameters Z_e^i and Z_o^i are calculated by inserting (1a) into the following equations [12]:

$$Z_e^i = \frac{1}{Y_0}\left[1 + \frac{J_{i-1,i}}{Y_0} + \left(\frac{J_{i-1,i}}{Y_0}\right)^2\right], \quad \text{(2a)}$$

$$Z_o^i = \frac{1}{Y_0}\left[1 - \frac{J_{i-1,i}}{Y_0} + \left(\frac{J_{i-1,i}}{Y_0}\right)^2\right], \quad \text{(2b)}$$

from which the layout parameters (w^i, g^i, ℓ^i) in Fig. 1 may be determined by conventional microwave techniques [13].

Numerical and Experimental Demonstration: To validate the concepts of the previous section, a microstrip implementation of the proposed planar reflective phaser is presented here. The resonators are etched on an Al_2O_3

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substrate with relative permittivity $\varepsilon_r = 9.9$, loss-tangent $\tan\delta = 0.001$, substrate thickness 10 mil and metal thickness 1 μm. The prescribed phaser response is a 4 ns-swing up-chirp linear group delay over the range $4.9 - 5.5$ GHz. Accordingly a 4^{th}-order phaser was synthesized. The synthesized geometrical parameters, indicated in Fig. 1, are listed in Tab. 1. The physical lengths the coupled-line section are slightly smaller than the effective quarter-wavelength at ω_0 after taking into account the open-end capacitive effect [14]. The first and last sections are 50 Ω transmission lines, whose dimensions are $w_0 = 9.543268$ mil, $\ell_0^1 = 208.201969$ mil and $\ell_0^2 = 205.260859$ mil. A photograph o the layout is shown in Fig. 3.

Table 1: Dimensions (unit: mil) for the $4.9 - 5.5$ GHz 4^{th} order microstrip reflective phaser with 4 ns group delay swing.

	I	II	III	IV
w^i	3.115516	7.303504	8.898937	9.300669
g^i	1.459563	3.802933	9.132362	16.092402
ℓ^i	213.085436	207.405863	205.772824	205.371623

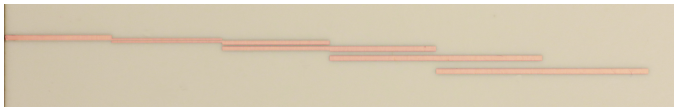
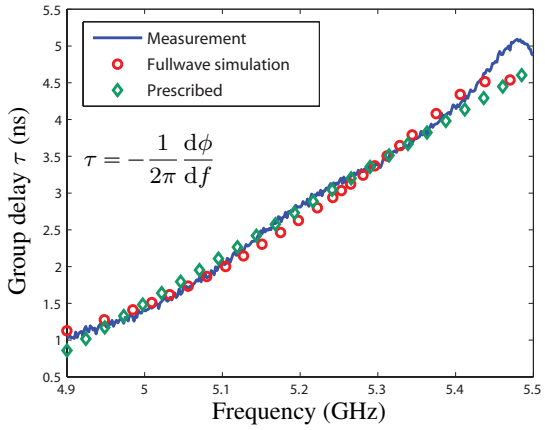
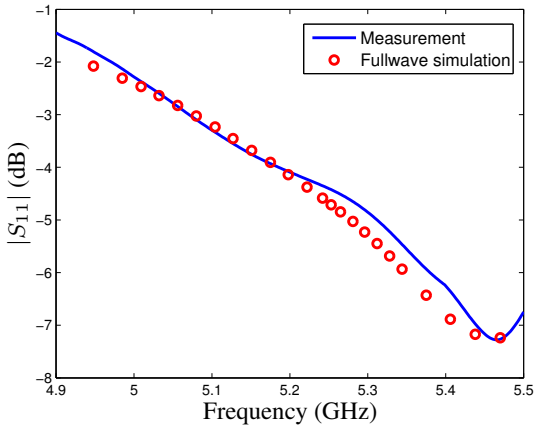


Fig. 3: Layout of the prototype, having the dimensions listed in Tab. 1.

The measured group delay response and reflection coefficient are plotted in Figs. 4(a) and Fig. 4(b), respectively. The prescribed group delay is also shown for comparison in the former case. Good agreement between measurement and simulation results is observed.



(a)



(b)

Fig. 4: Measurement results compared against fullwave simulation and prescribed (only shown for group delay response) ones, (a) group delay response, (b) magnitude response $|S_{11}|$.

Conclusion: A reflective phaser based on an open-ended edge-coupled line structure has been demonstrated. This phaser combines the benefits of high resolution inherent to cross-coupled resonator reflective phasers and of compactness of planar circuits. It may therefore find vast applications in R-ASP.

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